DATA SHEET

SILICON POWER TRANSISTOR **2SD1693**

NPN SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR LOW-FREQUENCY POWER AMPLIFIERS

FEATURES

• On-chip Zener diode

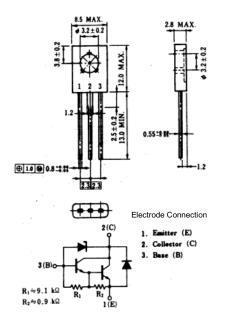
NEC

- High DC current gain due to Darlington connection
- Large current capacity and low VCE(sat)
- Large power dissipation TO-126 type power transistor
- Complementary transistor: 2SB1150

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Symbol	Ratings	Unit
Vсво	60 ±10	V
VCEO	60 ±10	V
Vebo	8.0	V
IC(DC)	±3.0	А
C(pulse)*	±5.0	А
P⊤ (T _A = 25°C)	1.3	W
P⊤ (Tc = 25°C)	15	W
Tj	150	°C
Tstg	-55 to +150	°C
	V_{CBO} V_{CEO} V_{EBO} $I_{C(DC)}$ $I_{C(pulse)}^{*}$ $P_{T} (T_{A} = 25^{\circ}C)$ $P_{T} (T_{C} = 25^{\circ}C)$ T_{j}	$\begin{tabular}{ c c c c } \hline V_{CBO} & 60 \pm 10 \\ \hline V_{CEO} & 60 \pm 10 \\ \hline V_{EBO} & 8.0 \\ \hline I_{C(DC)} & \pm 3.0 \\ \hline I_{C(pulse)}^* & \pm 5.0 \\ \hline P_T (T_A = 25^\circ C) & 1.3 \\ \hline P_T (T_c = 25^\circ C) & 15 \\ \hline T_j & 150 \\ \hline \end{tabular}$

PACKAGE DRAWING (UNIT: mm)



* PW \leq 10 ms, duty cycle \leq 50%

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to base voltage	Vсво	lc = 1.0 mA, I∈ = 0	50	60	70	V
Collector to emitter voltage	VCEO	Ic = 10 mA, R _{BE} = ∞	50	60	70	V
Collector to emitter voltage	VCEO(SUS)	Ic = 3.0 A, I _B = 3.0 mA, L = 1.0 mH	50			V
Collector cutoff current	Ісво	$V_{CB} = 40 \text{ V}, \text{ I}_{E} = 0$			10	μΑ
Collector cutoff current	ICEO	Vce = 40 V, R _{BE} = ∞			1.0	mA
DC current gain	hfe1**	Vce = 2.0 V, Ic = 1.5 A	2,000		20,000	
DC current gain	hfe2**	Vce = 2.0 V, Ic = 3.0 A	1,000			
Collector saturation voltage	VCE(sat)**	lc = 1.5 A, I _B = 1.5 mA		0.9	1.2	V
Base saturation voltage	VBE(sat)**	lc = 1.5 A, I _B = 1.5 mA		1.5	2.0	V
Turn-on time	ton	lc = 1.5 A		0.5		μs
Storage time	tstg	$I_{B1} = -I_{B2} = 1.5 \text{ mA}$		2.0		μs
Fall time	tr	$R_L = 27 \ \Omega, \ Vcc \cong 40 \ V$		1.0		μs

** Pulse test PW \leq 350 μ s, duty cycle \leq 2%/per pulsed

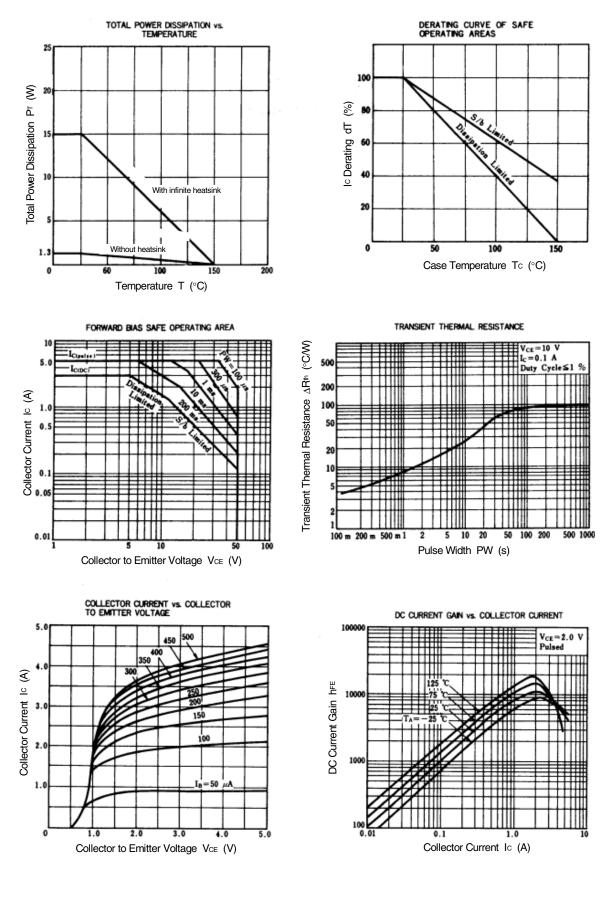
hfe CLASSIFICATION

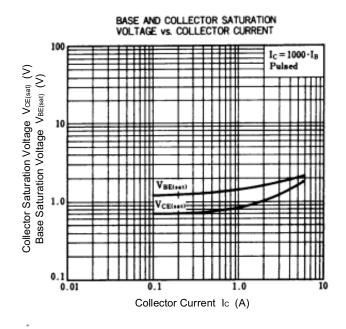
Marking	М	L	К
hfe1	2,000 to 5,000	4,000 to 12,000	3,000 to 20,000

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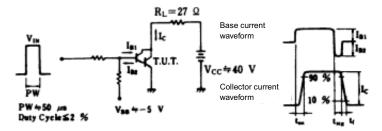
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TYPICAL CHARACTERISTICS (T_A = 25°C)





SWITCHING TIME (t_{on} , t_{stg} , t_f) TEST CIRCUIT



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